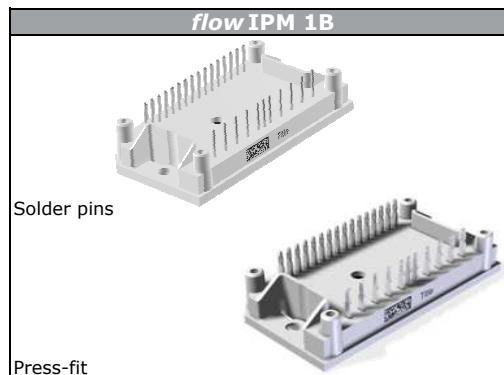


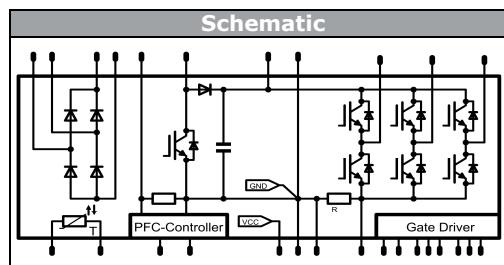
flow IPM 1B

600 V / 10 A

Features
• CIP-topology (converter + inverter + PFC)
• Optimized for PFC frequencies of 20kHz..100kHz and inverter frequencies of 4kHz..20kHz
• Integrated PFC controller circuit with programmable DC output voltage and PWM frequency
• Inverter gate drive inclusive bootstrap for high side power supply
• Over current and short circuit protection
• Integrated DC-capacitor
• Sense output of DC-current
• Temperature sensor
• Conclusive power flow, all power connections on one side, no input output X-ing
• Optional pre-applied thermal interface material



Target Applications
• Fans and Pumps
• AirCon
• Electrical Tools
• Low power industrial drive
Types
• 20-1B06IPB010RC-P955A40
• 20-PB06IPB010RC-P955A40Y

**Maximum Ratings** $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Input Rectifier Diode				
Repetitive peak reverse voltage	V_{RRM}		1600	V
DC forward current	I_{FAV}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ $T_c = 80^\circ\text{C}$	13 14	A
Surge (non-repetitive) forward current	I_{FSM}	$t_p = 10 \text{ ms}$ 50 Hz half sine wave	130	A
I^2t -value	I^2t		80	A^2s
Power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ $T_c = 80^\circ\text{C}$	15 23	W
Maximum Junction Temperature	T_{jmax}		150	$^\circ\text{C}$

PFC IGBT

Collector-emitter breakdown voltage	V_{CE}		650	V
DC collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ $T_c = 80^\circ\text{C}$	12 14	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	90	A
Turn off safe operating area		$V_{CE} \leq 650 \text{ V}, T_j \leq T_{op \text{ max}}$	90	A
Power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ $T_c = 80^\circ\text{C}$	19 29	W
Gate-emitter peak voltage	V_{GE}		± 20	V
Maximum Junction Temperature	T_{jmax}		175	$^\circ\text{C}$



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Maximum Ratings

 $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
PFC Inverse Diode				
Peak Repetitive Reverse Voltage	V_{RRM}		650	V
DC forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ $T_c = 80^\circ\text{C}$	5 7	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	12	A
Power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ $T_c = 80^\circ\text{C}$	10 15	W
Maximum Junction Temperature	T_{jmax}		175	$^\circ\text{C}$
PFC Diode				
Peak Repetitive Reverse Voltage	V_{RRM}		650	V
DC forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ $T_c = 80^\circ\text{C}$	10 14	A
Surge forward current	I_{FSM}	$t_p = 8,3 \text{ ms}$ 60 Hz half sine wave	180	A
I^2t -value	I^2t		130	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	60	A
Power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ $T_c = 80^\circ\text{C}$	17 26	W
Maximum Junction Temperature	T_{jmax}		175	$^\circ\text{C}$
Inverter Transistor				
Collector-emitter breakdown voltage	V_{CE}		600	V
DC collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ $T_c = 80^\circ\text{C}$	8 10	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	30	A
Turn off safe operating area		$V_{CE} \leq 600 \text{ V}$, $T_j \leq 150^\circ\text{C}$	20	A
Power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ $T_c = 80^\circ\text{C}$	16 25	W
Gate-emitter peak voltage	V_{GE}		± 20	V
Short circuit ratings	t_{SC} V_{CC}	$T_j \leq 150^\circ\text{C}$ $V_{GE} = 15 \text{ V}$	5 400	μs V
Maximum Junction Temperature	T_{jmax}		175	$^\circ\text{C}$
Inverter Diode				
Peak Repetitive Reverse Voltage	V_{RRM}		600	V
DC forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ $T_c = 80^\circ\text{C}$	8 10	A
Power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ $T_c = 80^\circ\text{C}$	14 22	W
Maximum Junction Temperature	T_{jmax}		175	$^\circ\text{C}$



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datasheet

Maximum Ratings

 $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
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PFC Shunt

DC forward current	I_F	$T_c = 25^\circ\text{C}$	10	A
Power dissipation	P_{tot}	$T_c = 25^\circ\text{C}$	10	W

PFC Controller*

VCC supply voltage	V_{CC}	V_{CC} common with gate driver IC	26	V
VSENSE voltage	V_{VSENSE}		26	V
Vsense Current	I_{VSENSE}		800	μA
FREQ pin voltage	V_{FREQ}		5,3	V
Maximum Junction Temperature	T_{jmax}		125	$^\circ\text{C}$

* for more information see infineon's datasheet ICE3PCS02

DC - Shunt

DC forward current	I_F		8	A
Power dissipation	P_{tot}		3,2	W

DC link Capacitor

Maximum DC voltage	V_{MAX}	$T_c = 25^\circ\text{C}$	500	V
--------------------	------------------	--------------------------	-----	---

Gate Driver*

Supply voltage	U_{CC}		20	V
Input voltage (LIN, HIN, EN)	U_{IN}		10	V
Output voltage (FAULT)	U_{OUT}		$\text{VCC}+0,5$	V

* for more information see infineon's datasheet 6ED003L02-F2

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{op}		-40...+($T_{\text{jmax}} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{is}	$t = 2\text{ s}$	DC voltage	4000	V
Creepage distance				min 12,7	mm
Clearance				min 12,7	mm
Comparative tracking index	CTI			>200	

Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
		V_{GE} [V] V_{GS} [V]	V_F [V] V_{CE} [V] V_{DS} [V]	I_C [A] I_F [A] I_D [A]	T_1 [°C]	Min	Typ	Max			
Input Rectifier Diode											
Forward voltage	V_F			7	25 125			1,04 0,97		V	
Threshold voltage (for power loss calc. only)	V_{to}			7	25 125			0,87 0,74		V	
Slope resistance (for power loss calc. only)	r_t			7	25 125			25 33		mΩ	
Reverse current	I_r		1600		25				0,01	mA	
Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4\text{W/mK}$						4,56		K/W	
PFC IGBT											
Gate emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$		0,0003	25	3,3	4	4,7		V	
Collector-emitter saturation voltage	V_{CESat}		15	10	25 125			1,28 1,28	1,9	V	
Collector-emitter cut-off	I_{CES}		0	650	25				0,04	mA	
Turn-on delay time	$t_{d(on)}$	$U_{CC} = 15 \text{ V}$	400	10	25 125		27 28			ns	
Rise time	t_r				25 125		5 7				
Turn-off delay time	$t_{d(off)}$				25 125		122 154				
Fall time	t_f				25 125		2 2				
Turn-on energy loss	E_{on}				25 125		0,1516 0,2417			mWs	
Turn-off energy loss	E_{off}				25 125		0,0317 0,0583				
Input capacitance	C_{ies}	$f = 1 \text{ MHz}$	0	25			2100			pF	
Output capacitance	C_{oss}						45				
Reverse transfer capacitance	C_{rss}						7,7				
Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4\text{W/mK}$						4,96		K/W	
PFC Inverse Diode											
Diode forward voltage	V_F			6	25 125	1,23	1,73 1,59	2,15		V	
Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4\text{W/mK}$						9,56		K/W	
PFC Diode											
Forward voltage	V_F			10	25 125			1,64 1,63	2,26	V	
Reverse leakage current	I_{rm}	$U_{CC} = 15 \text{ V}$	400	10	25				5	μA	
Peak recovery current	I_{RRM}				25 125		15 19			A	
Reverse recovery time	t_{rr}				25 125		22 36			ns	
Reverse recovery charge	Q_{rr}				25 125		0,2008 0,4358			μC	
Reverse recovered energy	E_{rec}				25 125		0,0150 0,0504			mWs	
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$				25 125		2033 891			A/μs	
Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4\text{W/mK}$						5,48		K/W	
PFC Shunt											
R1 value	R							40		mΩ	

Characteristic Values

Parameter	Symbol	Conditions					Value			Unit
		V_{GE} [V] V_{GS} [V]	V_F [V] V_{CE} [V] V_{DS} [V]	I_C [A] I_F [A] I_D [A]	T_J [°C]	Min	Typ	Max		
Inverter Transistor										
Gate emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,00017	25	4,4	5	5,6	V
Collector-emitter saturation voltage*	V_{CESat}		15		10	25 125	1,7	2,20 2,32	2,95	V
Collector-emitter cut-off current incl. Diode	I_{CES}		0	600		25			0,1	mA
Gate-emitter leakage current	I_{GES}		20	0		25			120	nA
Integrated Gate resistor	R_{gint}						none			Ω
Turn-on delay time **	$t_{d(on)}$	$U_{CC} = 15 \text{ V}$ $U_{IN} = 5 \text{ V}$	400	6	25 125		582 631			ns
Rise time	t_r				25 125		20 25			
Turn-off delay time **	$t_{d(off)}$				25 125		837 950			
Fall time	t_f				25 125		16 22			
Turn-on energy loss	E_{on}				25 125		0,1950 0,3241			mWs
Turn-off energy loss	E_{off}				25 125		0,1611 0,2042			
Input capacitance	C_{ies}	$f = 1 \text{ MHz}$	0	25			655			pF
Output capacitance	C_{oss}						37			
Reverse transfer capacitance	C_{rss}						22			
Gate charge	Q_G		15	480	10	25		64		nC
Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4 \text{ W/mK}$						5,79		K/W
* chip data										
** including gate driver										
Inverter Diode										
Diode forward voltage	V_F				10	25 125	1,5	2,23 2,18	2,85	V
Peak reverse recovery current	I_{RRM}	$U_{CC} = 15 \text{ V}$ $U_{IN} = 5 \text{ V}$	400	6		25 125		6 6		A
Reverse recovery time	t_{rr}					25 125		179 276		ns
Reverse recovered charge	Q_{rr}					25 125		0,3566 0,6738		μC
Peak rate of fall of recovery current	$(dI_{rr}/dt)_{max}$					25 125		181 46		A/μs
Reverse recovered energy	E_{rec}					25 125		0,0867 0,1610		mWs
Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4 \text{ W/mK}$						6,66		K/W
DC - Shunt										
R2 value	R					25		25		$\text{m}\Omega$
DC link Capacitor										
C Value	C							100		nF



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Characteristic Values

Parameter	Symbol	Conditions					Value			Unit
		V_{GE} [V] V_{GS} [V]	V_T [V] V_{CE} [V] V_{DS} [V]	I_C [A] I_F [A] I_D [A]	T_1 [°C]	Min	Typ	Max		

Gate Driver

Supply voltage	U_{CC}	$U_{LIN} = 0 \text{ V}; U_{HIN}=3,3 \text{ V}$ $U_{CC} = 15 \text{ V}$					25	13	15	17,5	V	
Quiescent Vcc supply current	I_{QCC}							1,3	2		mA	
Input voltage (LIN, HIN, EN)	U_{IN}							0		5	V	
Logic "0" input voltage (LIN, HIN)	U_{IH}							1,7	2,1	2,4		
Logic "1" input voltage (LIN, HIN)	U_{IL}							0,7	0,9	1,1		
Positive going threshold voltage (EN)	$U_{EN,TH+}$							1,9	2,1	2,3		
Negative going threshold voltage (EN)	$U_{EN,TH-}$							1,1	1,3	1,5		
Input clamp voltage (LIN, HIN, EN)	$U_{IN,CLAMP}$							9	10,3	12		
ITRIP positive going threshold	$U_{TR,TH+}$	$U_{LIN} = 3,3 \text{ V}$						380	445	510	mV	
Input bias current LIN high	I_{LIN+}								70	100	μA	
Input bias current LIN low	I_{LIN-}								110	200		
Input bias current HIN high	I_{HIN+}								70	100		
Input bias current HIN low	I_{HIN-}								110	120		
Input bias current EN high	I_{EN+}								45	120		
Output voltage (FAULT)	U_{FLT}							0		U_{CC}	V	
Low on resistor of pull down trans. (FAULT)	$R_{ON,FLT}$								45,0	100	Ω	
Pulse width for ON or OFF	t_{IN}	$U_{LIN/HIN} = 0 \text{ V or } 3,3 \text{ V}$						1			μs	
Turn-on propagation delay (LIN, HIN)	t_{ON}							400	530	800	ns	
Turn-off propagation delay (LIN, HIN)	t_{OFF}							360	490	760		
FAULT reset time	t_{RST}								4		ms	
Fixed deadtime between high and low side	t_{DT}							150	310		ns	

PFC Controller

Supply voltage*	V_{CC}	$C_L = 1 \text{ nF}$						15		26	V
VCC turn-on threshold	V_{CCon}							11,5	12,0	12,9	V
VCC turn-off threshold	V_{CCUVLO}							10,5	11,0	11,9	V
Operating current with active GATE	I_{CCHG}								6,4	8,5	mA
Operating current during standby	I_{CCstby}								3,5	4,7	mA
PFC switching frequency	F_{SWnom}								20		kHz
PFC disable threshold	V_{disPFC}							14			V
DC link voltage	$DC2+$							325		410	V
DC link treshold (OVP1) low to high	$V_{OVP1L2H}$	$relative to output voltage$ OVP1 values varies with external resistor Feedback voltage $V_{DCinb}/130$ can be measured at VSENSE pin							108		%
DC link treshold (OVP1) high to low	$V_{OVP1H2L}$								100		%
Blanking time for OVP1	t_{OVP1}								12		μs
DC link treshold (OVP1) hysteresis	V_{OVP1_HYS}							6	8	11	%
DC link treshold (OVP2) low to high	V_{OVP2_L2H}							428	443	460	V
DC link treshold (OVP2) high to low	V_{OVP2_H2L}								92		%
Blanking time for OVP2	t_{OVP2}								12		μs

*recommended supply voltage range: 15-18 V

**switching frequency is setable by an external resistor between pins 14-16 (see figure on page27 for values)

***DC link voltage is setable by an external resistor between pins 14-15 (see figure on page27 for values)

Thermistor

Rated resistance	R					25		22000		Ω
Deviation of R_{100}	$\Delta R/R$	$R_{100} = 1486 \Omega$				100	-12		12	%
Power dissipation	P					25		200		mW
Power dissipation constant						25		2		mW/K
B-value	$B_{(25/50)}$	Tol. ±3%				25		3950		K
B-value	$B_{(25/100)}$	Tol. ±3%				25		3998		K
Vincotech NTC Reference								B		



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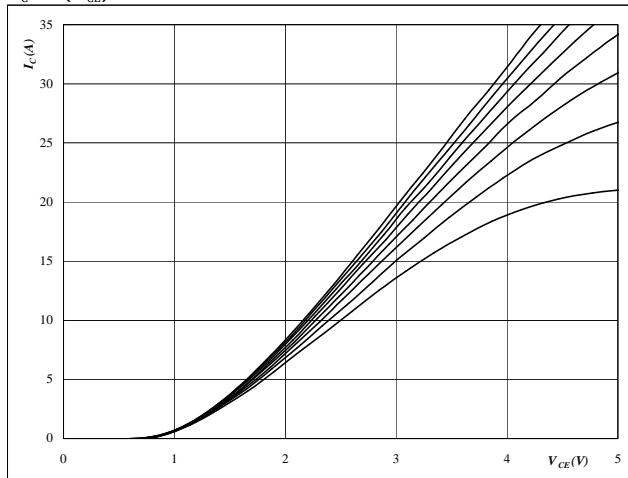
Output Inverter

Figure 1

Output inverter IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$



At

$$t_p = 250 \mu\text{s}$$

$$T_j = 25^\circ\text{C}$$

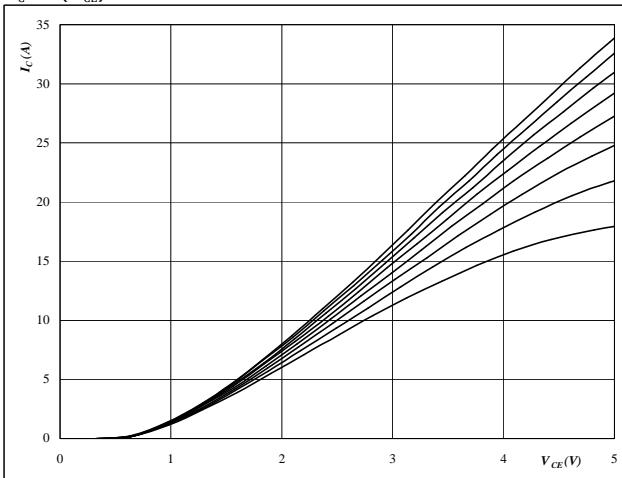
U_{CC} from 10 V to 17 V in steps of 1 V

Figure 2

Output inverter IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$



At

$$t_p = 250 \mu\text{s}$$

$$T_j = 125^\circ\text{C}$$

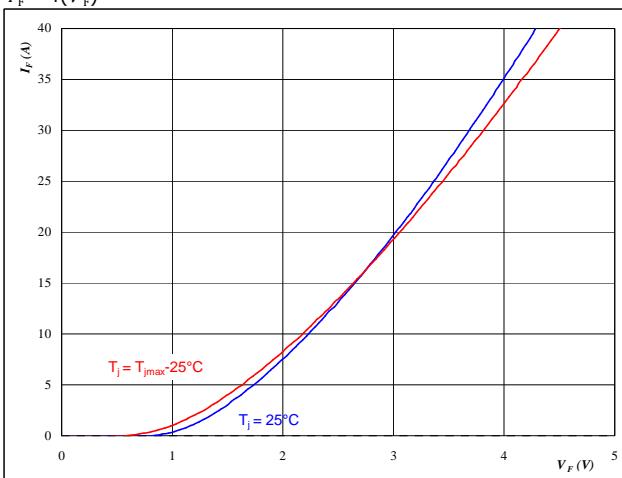
U_{CC} from 10 V to 17 V in steps of 1 V

Figure 3

Output inverter FWD

Typical diode forward current as a function of forward voltage

$$I_F = f(V_F)$$



At

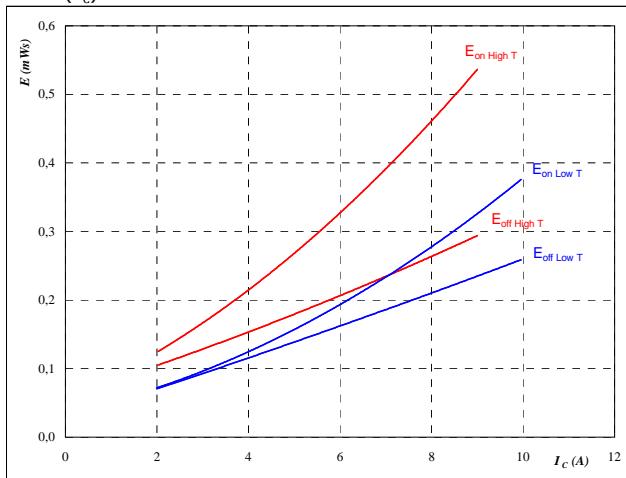
$$t_p = 250 \mu\text{s}$$

Output Inverter

Figure 4 Output inverter IGBT

**Typical switching energy losses
as a function of collector current**

$$E = f(I_C)$$



With an inductive load at

$$T_j = 25/125 \quad ^\circ\text{C}$$

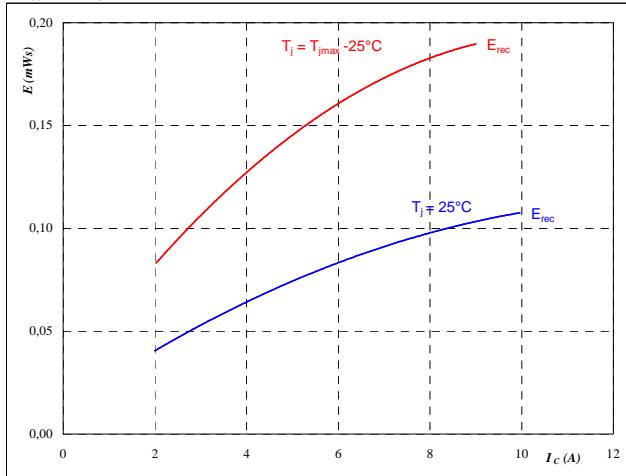
$$V_{CE} = 400 \quad \text{V}$$

$$U_{CC} = 15 \quad \text{V}$$

Figure 5 Output inverter FWD

**Typical reverse recovery energy loss
as a function of collector current**

$$E_{rec} = f(I_C)$$



With an inductive load at

$$T_j = 25/125 \quad ^\circ\text{C}$$

$$V_{CE} = 400 \quad \text{V}$$

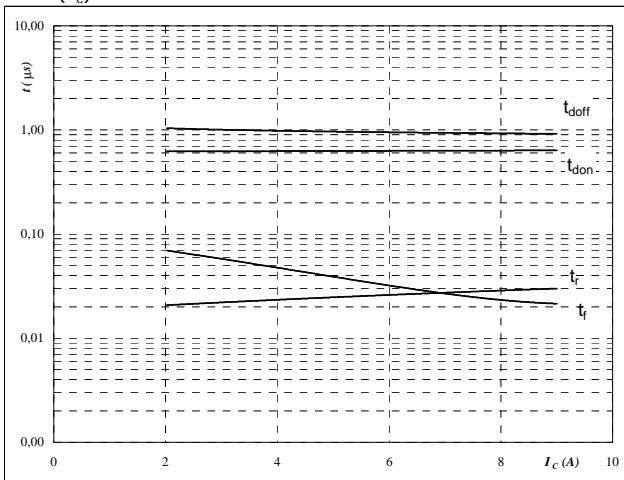
$$U_{CC} = 15 \quad \text{V}$$

Output Inverter

Figure 6 Output inverter IGBT

Typical switching times as a function of collector current

$$t = f(I_c)$$



With an inductive load at

$$T_j = 125 \text{ } ^\circ\text{C}$$

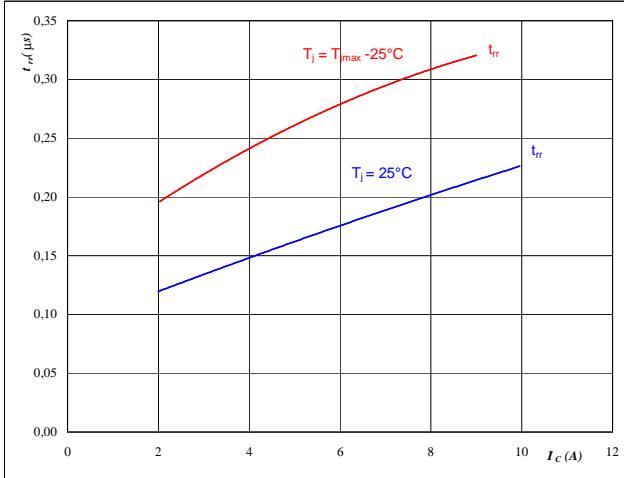
$$V_{CE} = 400 \text{ V}$$

$$U_{CC} = 15 \text{ V}$$

Figure 7 Output inverter FWD

Typical reverse recovery time as a function of collector current

$$t_{rr} = f(I_c)$$



At

$$T_j = 25/125 \text{ } ^\circ\text{C}$$

$$V_{CE} = 400 \text{ V}$$

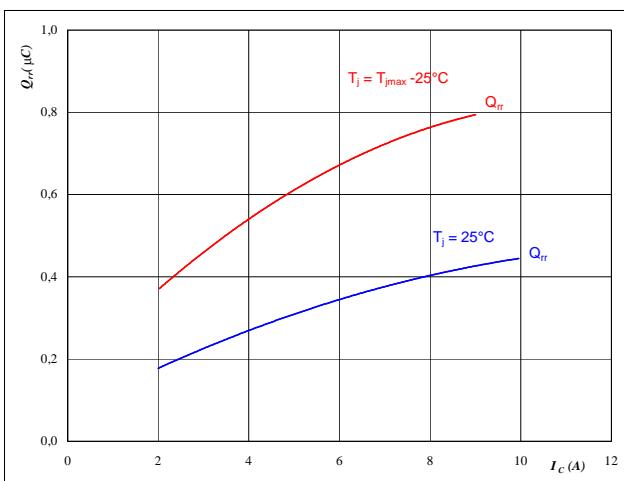
$$U_{CC} = 15 \text{ V}$$

Output Inverter

Figure 8 Output inverter FWD

Typical reverse recovery charge as a function of collector current

$$Q_{rr} = f(I_c)$$



At

$$T_j = 25/125 \quad {}^\circ\text{C}$$

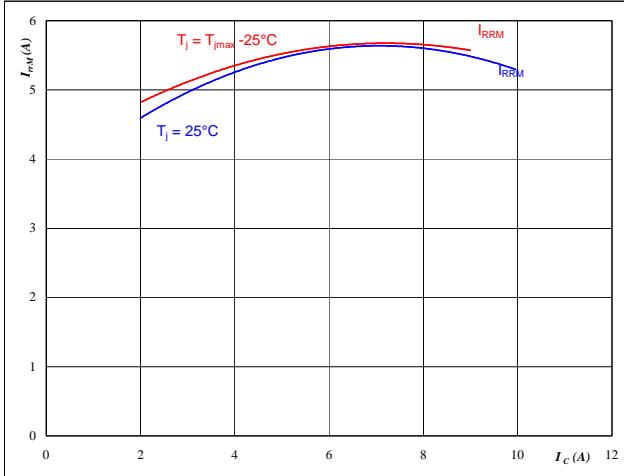
$$V_{CE} = 400 \quad \text{V}$$

$$U_{CC} = 15 \quad \text{V}$$

Figure 9 Output inverter FWD

Typical reverse recovery current as a function of collector current

$$I_{RRM} = f(I_c)$$



At

$$T_j = 25/125 \quad {}^\circ\text{C}$$

$$V_{CE} = 400 \quad \text{V}$$

$$U_{CC} = 15 \quad \text{V}$$



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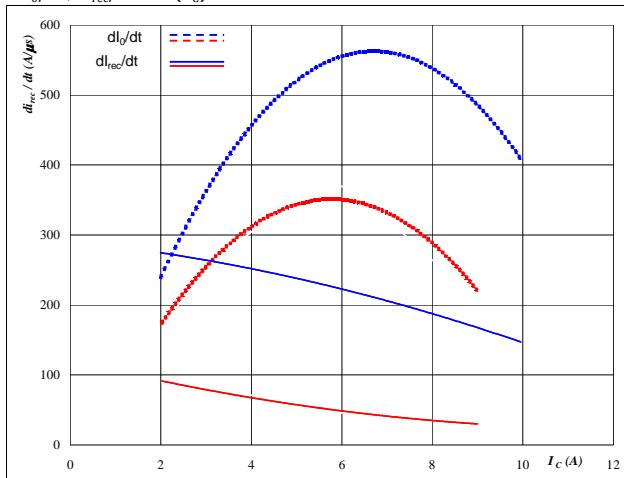
datasheet

Output Inverter

Figure 10 Output inverter FWD

**Typical rate of fall of forward
and reverse recovery current as a
function of collector current**

$$dI_0/dt, dI_{rec}/dt = f(I_C)$$

**At**

$$T_j = 25/125 \quad ^\circ C$$

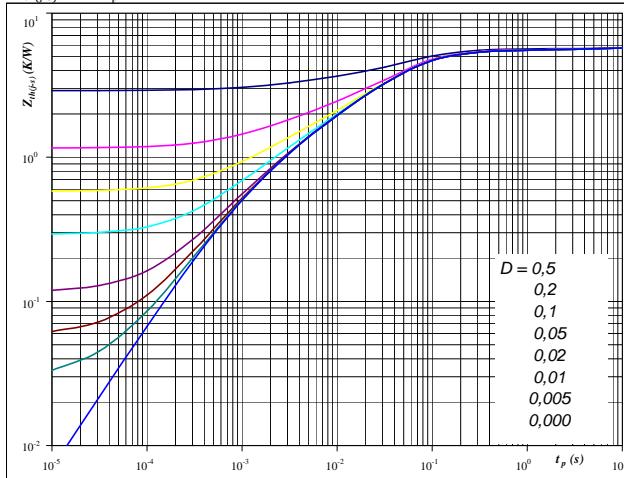
$$V_{CE} = 400 \quad V$$

$$U_{CC} = 15 \quad V$$

Figure 11 Output inverter IGBT

**IGBT transient thermal impedance
as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$

**At**

$$D = t_p / T$$

$$R_{th(j-s)} = 5,79 \quad K/W$$

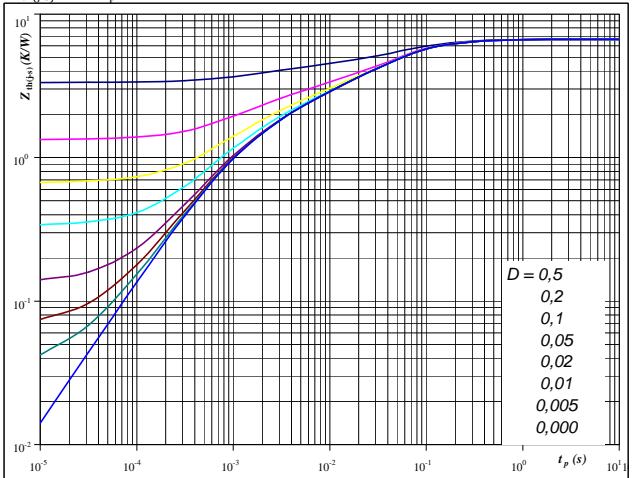
IGBT thermal model values

R (K/W)	Tau (s)
0,30	6,6E+00
0,61	2,1E-01
3,21	4,9E-02
0,84	1,0E-02
0,56	2,9E-03
0,26	7,4E-04

Figure 12 Output inverter FWD

**FWD transient thermal impedance
as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$

**At**

$$D = t_p / T$$

$$R_{th(j-s)} = 6,66 \quad K/W$$

FWD thermal model values

R (K/W)	Tau (s)
0,62	3,1E-01
3,07	5,4E-02
0,76	2,3E-02
1,19	4,7E-03
0,95	9,8E-04
0,08	7,5E-04

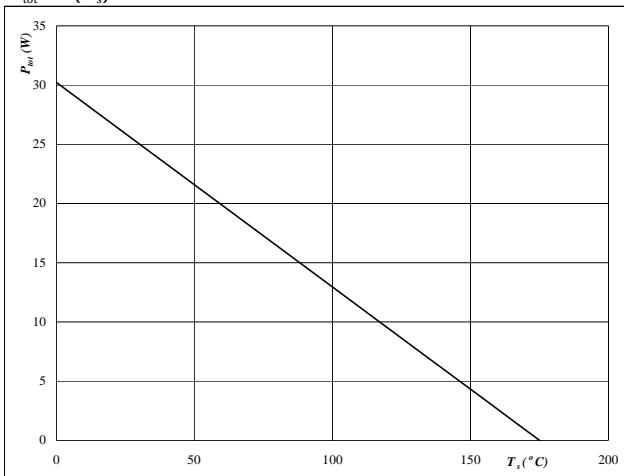
Output Inverter

Figure 13

Output inverter IGBT

Power dissipation as a function of heatsink temperature

$$P_{\text{tot}} = f(T_s)$$


At

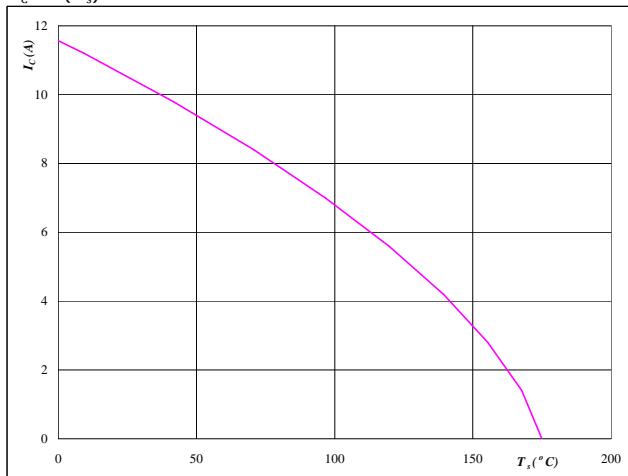
$$T_j = 175 \quad ^\circ\text{C}$$

Figure 14

Output inverter IGBT

Collector current as a function of heatsink temperature

$$I_C = f(T_s)$$


At

$$T_j = 175 \quad ^\circ\text{C}$$

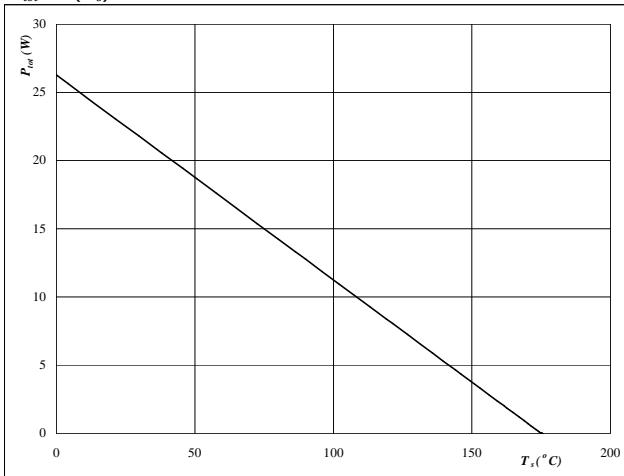
$$U_{CC} = 15 \quad \text{V}$$

Figure 15

Output inverter FWD

Power dissipation as a function of heatsink temperature

$$P_{\text{tot}} = f(T_s)$$


At

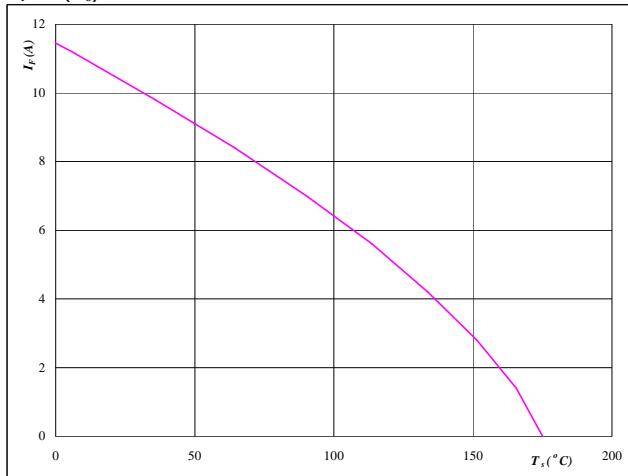
$$T_j = 175 \quad ^\circ\text{C}$$

Figure 16

Output inverter FWD

Forward current as a function of heatsink temperature

$$I_F = f(T_s)$$


At

$$T_j = 175 \quad ^\circ\text{C}$$



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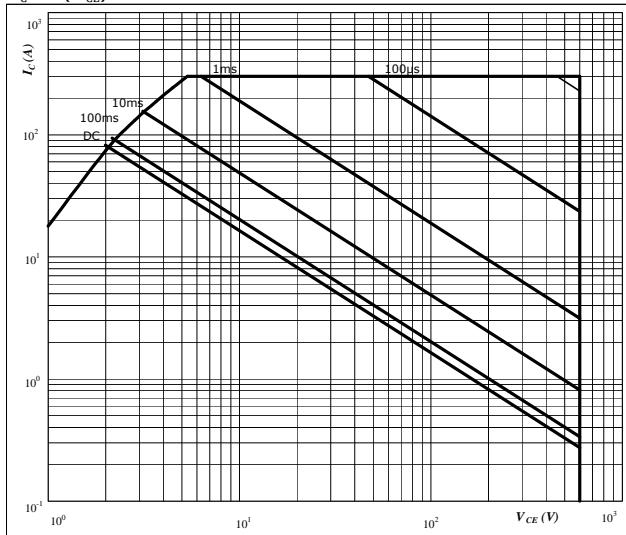
datasheet

Output Inverter

Figure 17 Output inverter IGBT

**Safe operating area as a function
of collector-emitter voltage**

$$I_C = f(V_{CE})$$



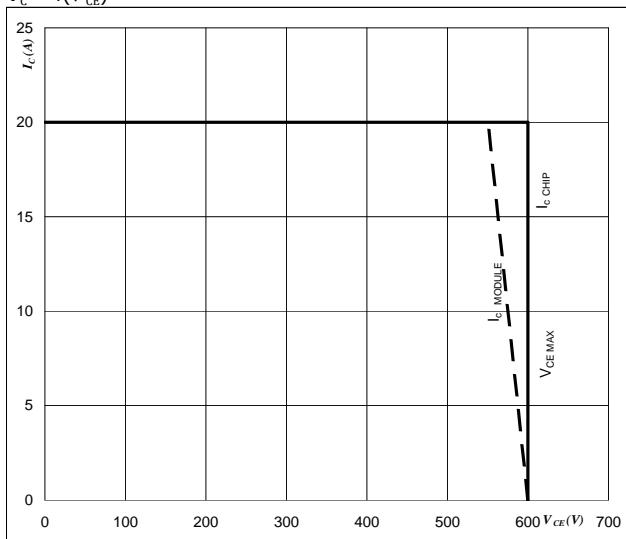
At

$$\begin{aligned} T_j &\leq T_{jmax} \\ U_{CC} &= 15 \quad V \end{aligned}$$

Figure 18 Output inverter IGBT

Reverse bias safe operating area

$$I_C = f(V_{CE})$$



At

$$T_j = T_{jmax} - 25 \quad ^\circ C$$



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datasheet

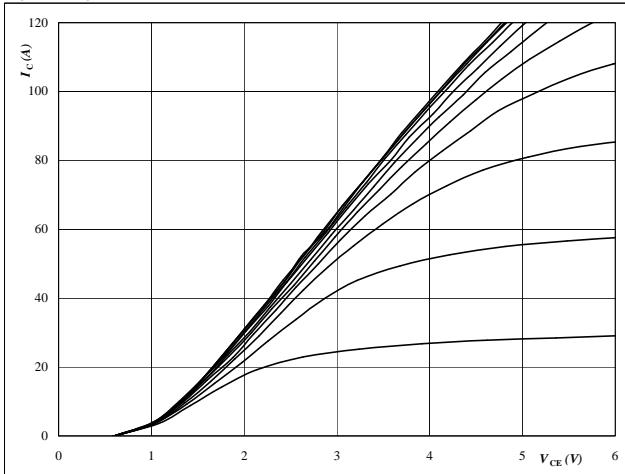
PFC

Figure 1

Typical output characteristics

PFC IGBT

$$I_C = f(V_{CE})$$



At

$$t_p = 250 \mu\text{s}$$

$$T_j = 25^\circ\text{C}$$

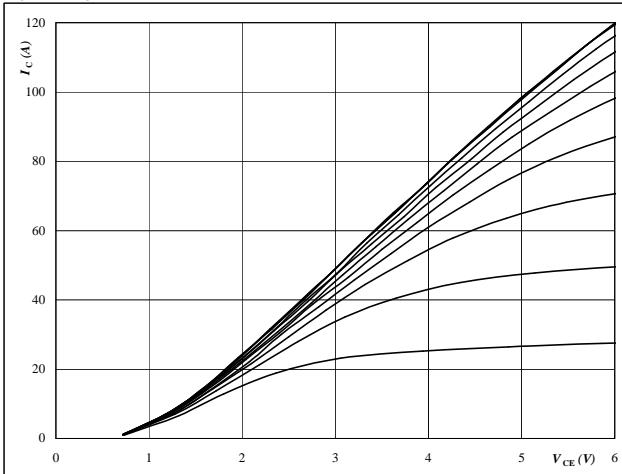
U_{CC} from 7 V to 17 V in steps of 1 V

Figure 2

Typical output characteristics

PFC IGBT

$$I_C = f(V_{CE})$$



At

$$t_p = 250 \mu\text{s}$$

$$T_j = 125^\circ\text{C}$$

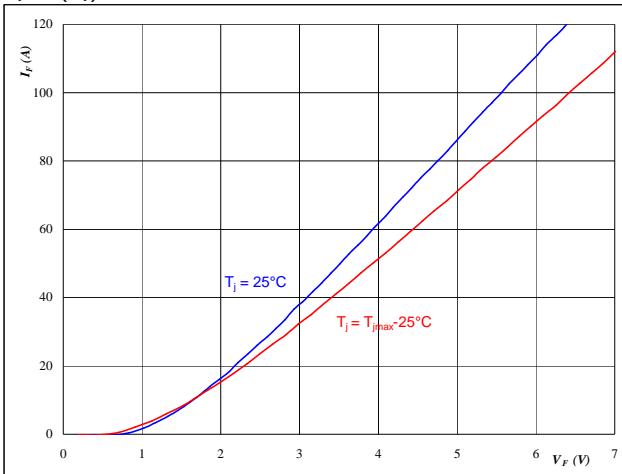
U_{CC} from 7 V to 17 V in steps of 1 V

Figure 3

PFC FWD

Typical diode forward current as a function of forward voltage

$$I_F = f(V_F)$$



At

$$t_p = 250 \mu\text{s}$$



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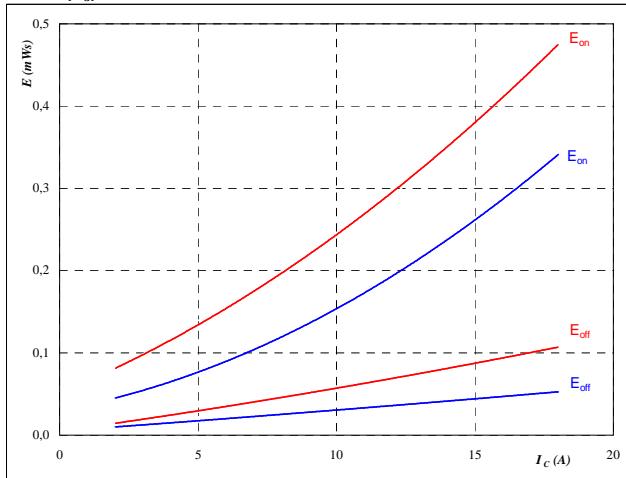
20-1B06IPB010RC-P955A40

datasheet

PFC

Figure 4 PFC IGBT**Typical switching energy losses
as a function of collector current**

$$E = f(I_c)$$



With an inductive load at

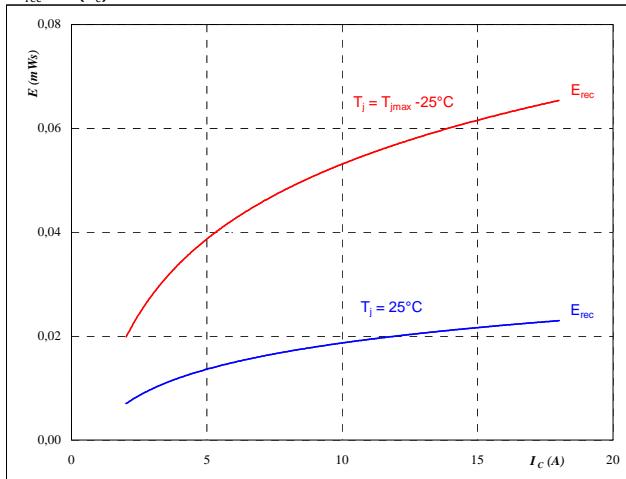
$$T_j = 25/125 \quad ^\circ C$$

$$V_{CE} = 400 \quad V$$

$$U_{CC} = 15 \quad V$$

Figure 5 PFC IGBT**Typical reverse recovery energy loss
as a function of collector current**

$$E_{rec} = f(I_c)$$



With an inductive load at

$$T_j = 25/125 \quad ^\circ C$$

$$V_{CE} = 400 \quad V$$

$$U_{CC} = 15 \quad V$$



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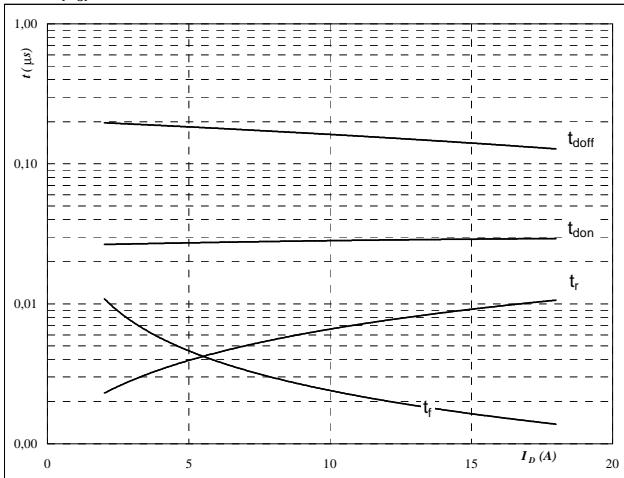
datasheet

PFC

Figure 6 PFC IGBT

Typical switching times as a function of collector current

$$t = f(I_c)$$



With an inductive load at

$$T_j = 125 \text{ } ^\circ\text{C}$$

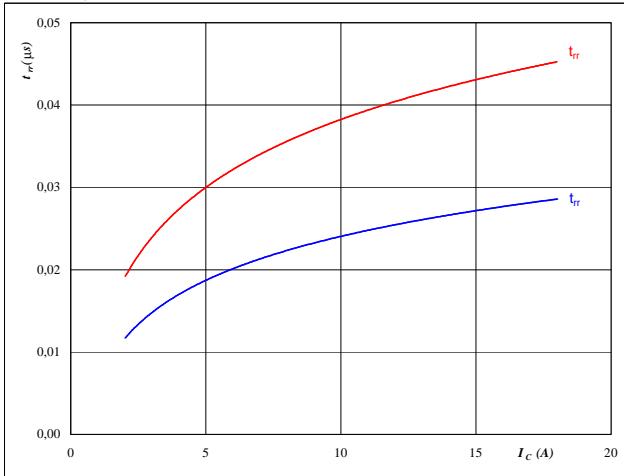
$$V_{CE} = 400 \text{ V}$$

$$U_{CC} = 15 \text{ V}$$

Figure 7 PFC FWD

Typical reverse recovery time as a function of collector current

$$t_{rr} = f(I_c)$$



At

$$T_j = 25/125 \text{ } ^\circ\text{C}$$

$$V_{CE} = 400 \text{ V}$$

$$U_{CC} = 15 \text{ V}$$



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datasheet

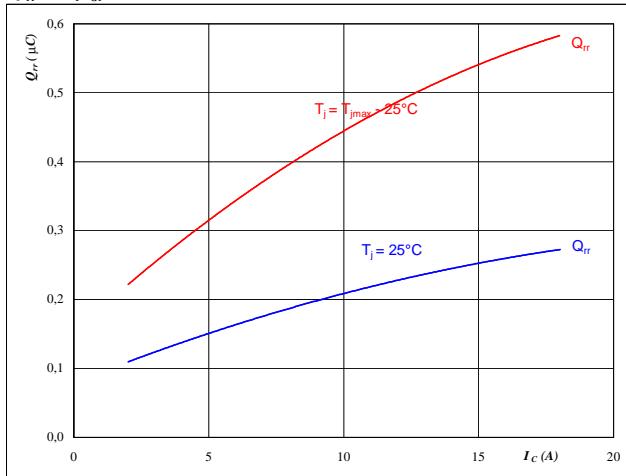
PFC

Figure 8

PFC FWD

Typical reverse recovery charge as a function of collector current

$$Q_{rr} = f(I_c)$$



At

$$T_j = 25/125 \quad ^\circ\text{C}$$

$$V_{CE} = 400 \quad \text{V}$$

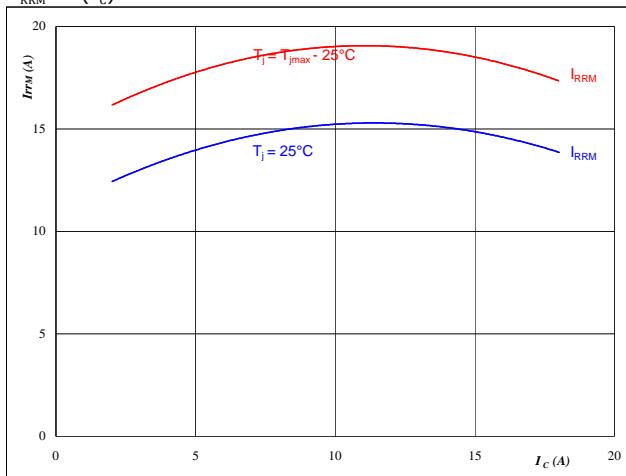
$$U_{CC} = 15 \quad \text{V}$$

Figure 9

PFC FWD

Typical reverse recovery current as a function of collector current

$$I_{RRM} = f(I_c)$$



At

$$T_j = 25/125 \quad ^\circ\text{C}$$

$$V_{CE} = 400 \quad \text{V}$$

$$U_{CC} = 15 \quad \text{V}$$



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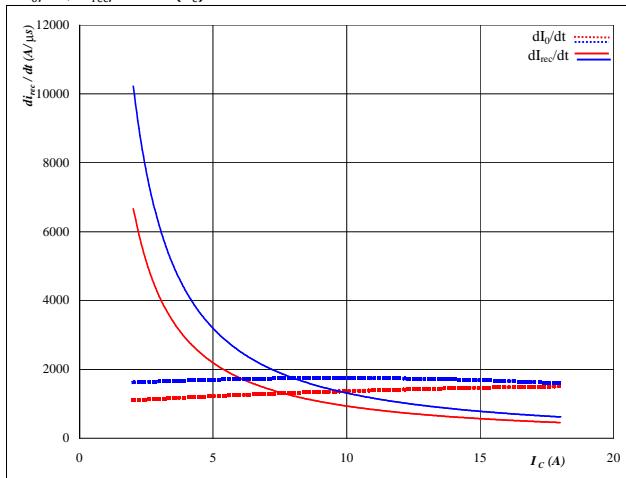
PFC

Figure 10

PFC FWD

**Typical rate of fall of forward
and reverse recovery current as a
function of collector current**

$$dI_0/dt, dI_{rec}/dt = f(I_c)$$



At

$$T_j = 25/125 \quad {}^\circ\text{C}$$

$$V_{CE} = 400 \quad \text{V}$$

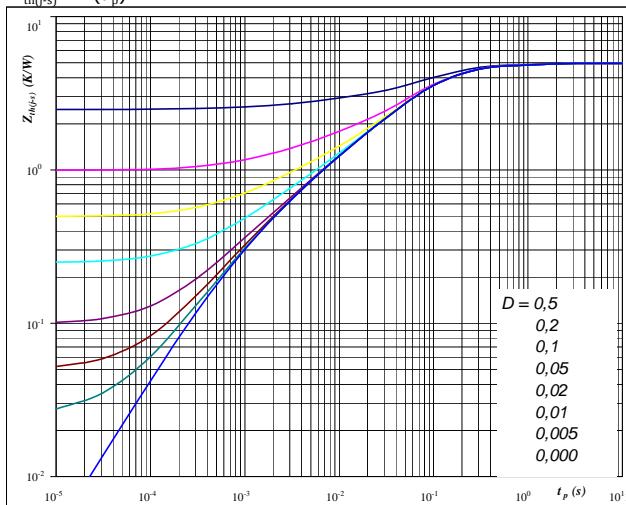
$$U_{CC} = 15 \quad \text{V}$$

Figure 11

PFC IGBT

**IGBT transient thermal impedance
as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$



At

$$D = t_p / T$$

$$R_{th(j-s)} = 4,96 \quad \text{K/W}$$

IGBT thermal model values

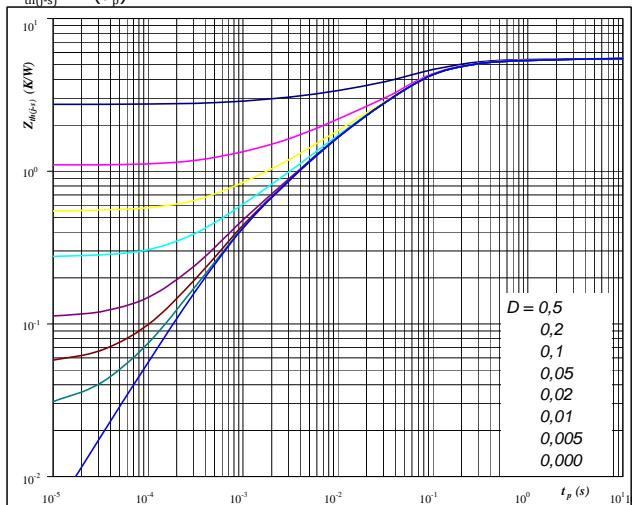
R (K/W)	Tau (s)
0,42	0,775
2,554	0,104
1,288	0,033
0,560	0,004
0,142	0,001

Figure 12

PFC FWD

**FWD transient thermal impedance
as a function of pulse width**

$$Z_{th(j-s)} = f(t_p)$$



At

$$D = t_p / T$$

$$R_{th(j-s)} = 5,48 \quad \text{K/W}$$

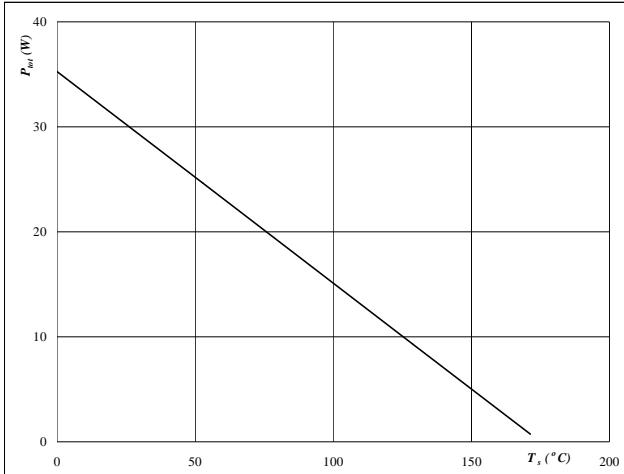
FWD thermal model values

R (K/W)	Tau (s)
0,20	2,872
0,69	0,254
3,28	0,055
0,98	0,007
0,33	0,001

PFC

Figure 13
Power dissipation as a function of heatsink temperature

$$P_{\text{tot}} = f(T_s)$$

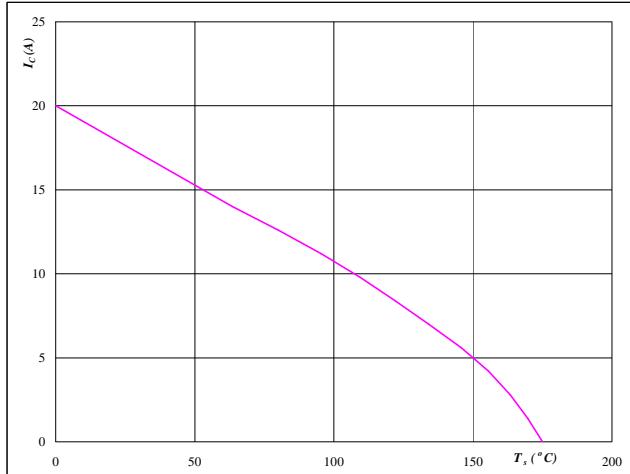


At
 $T_j = 175 \text{ } ^\circ\text{C}$

PFC IGBT

Figure 14
Collector current as a function of heatsink temperature

$$I_C = f(T_s)$$

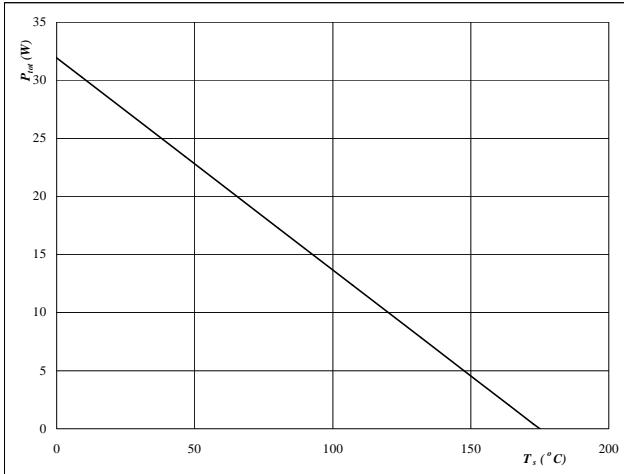


At
 $T_j = 175 \text{ } ^\circ\text{C}$
 $U_{CC} = 15 \text{ V}$

PFC IGBT

Figure 15
Power dissipation as a function of heatsink temperature

$$P_{\text{tot}} = f(T_s)$$

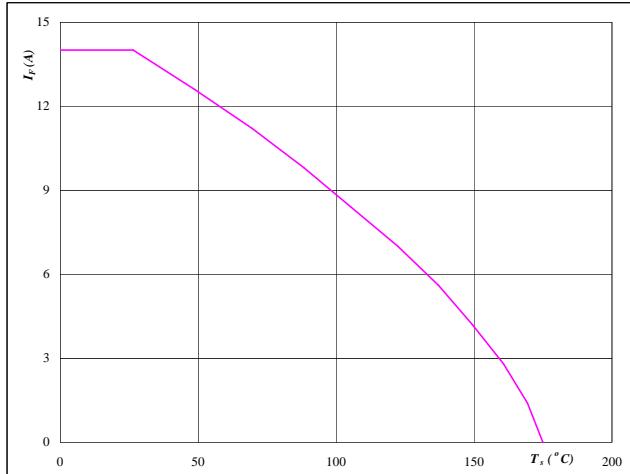


At
 $T_j = 175 \text{ } ^\circ\text{C}$

PFC FWD

Figure 16
Forward current as a function of heatsink temperature

$$I_F = f(T_s)$$



At
 $T_j = 175 \text{ } ^\circ\text{C}$

PFC FWD



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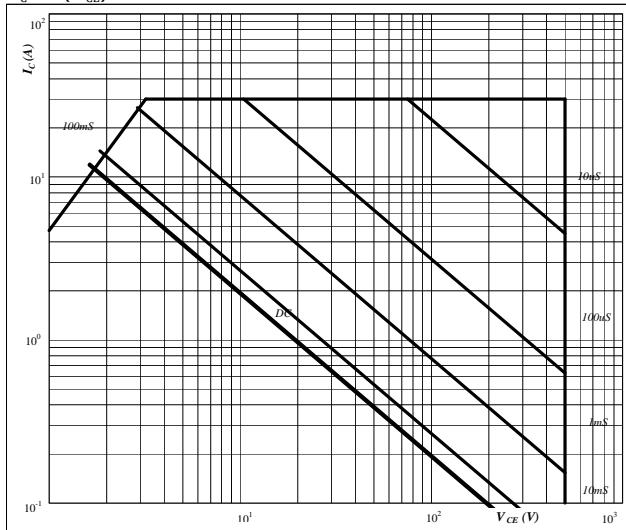
datasheet

PFC

Figure 17 PFC IGBT

**Safe operating area as a function
of collector-emitter voltage**

$$I_C = f(V_{CE})$$



At

D = single pulse

T_s = 80 °C

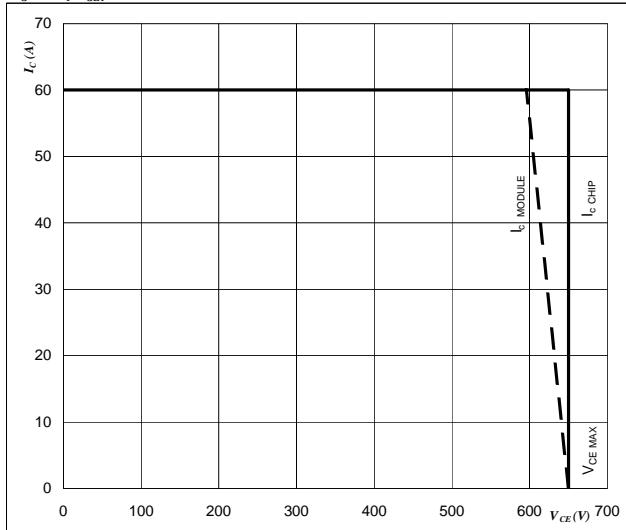
U_{CC} = 15 V

T_j = T_{jmax}

Figure 18 PFC IGBT

Reverse bias safe operating area

$$I_C = f(V_{CE})$$



At

T_j = $T_{jmax} - 25$ °C



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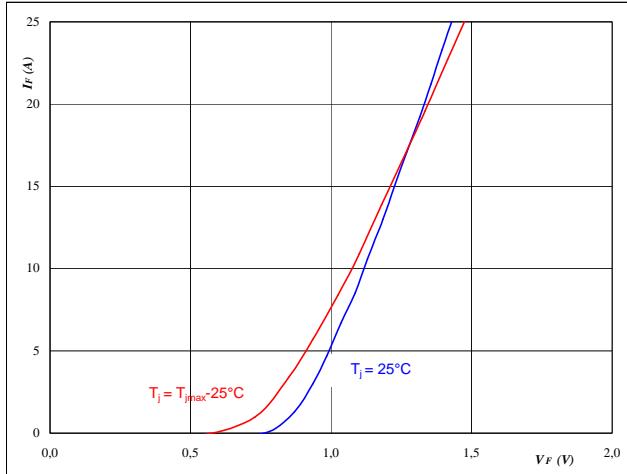
20-1B06IPB010RC-P955A40

datasheet

Input Rectifier Diode

Figure 1
Typical diode forward current as
a function of forward voltage

$$I_F = f(V_F)$$

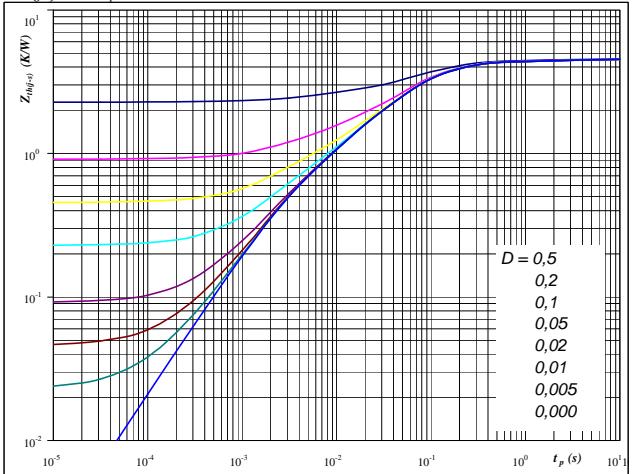
**At**

$$t_p = 250 \mu\text{s}$$

Rectifier Diode

Figure 2
Diode transient thermal impedance
as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$

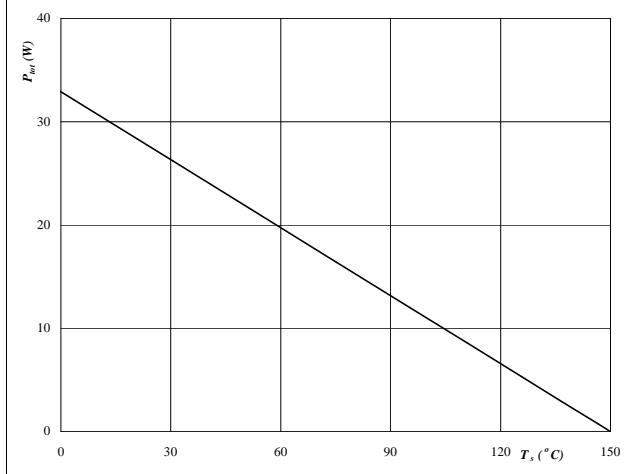
**At**

$$D = t_p / T$$

$$R_{th(j-s)} = 4,56 \text{ K/W}$$

Figure 3
Power dissipation as a
function of heatsink temperature

$$P_{tot} = f(T_s)$$

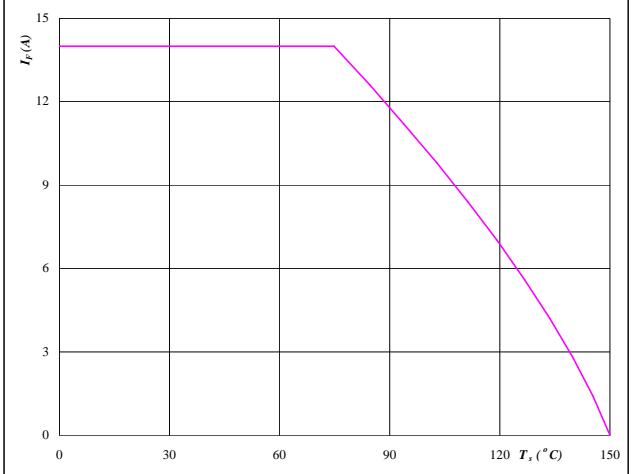
**At**

$$T_j = 150 ^\circ\text{C}$$

Rectifier diode

Figure 4
Forward current as a
function of heatsink temperature

$$I_F = f(T_s)$$

**At**

$$T_j = 150 ^\circ\text{C}$$

Shunt

Figure 1
Pulse Power R1

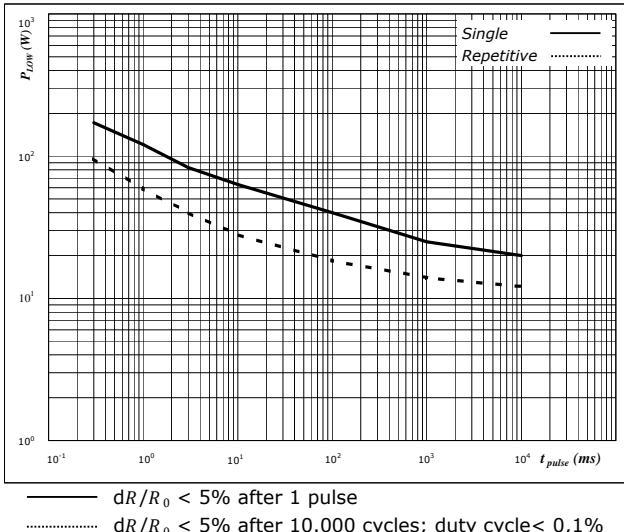
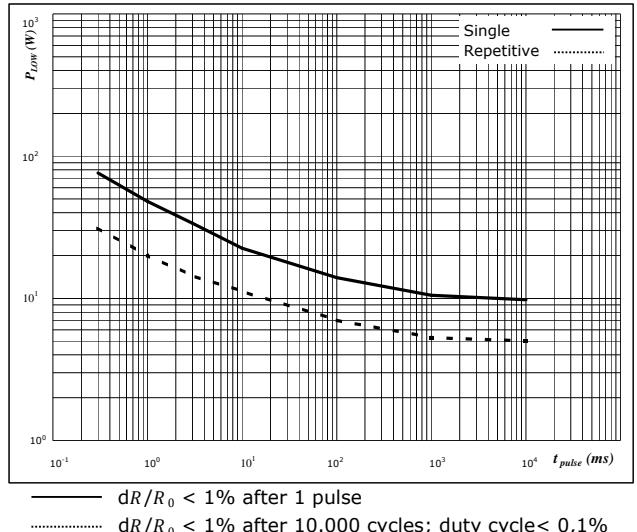


Figure 2
DC Shunt





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datasheet

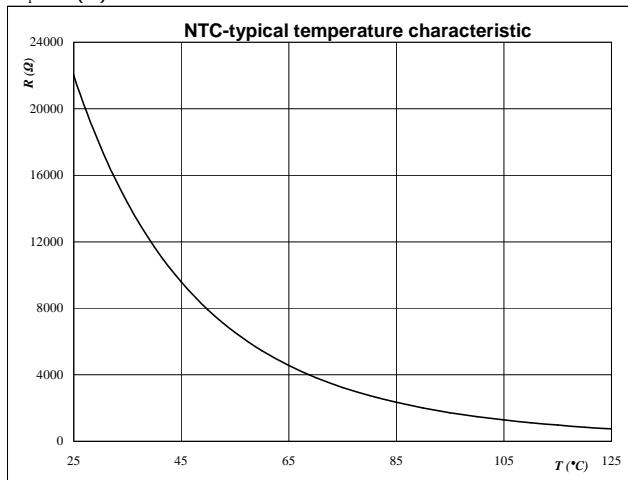
Thermistor

Figure 1

Thermistor

**Typical NTC characteristic
as a function of temperature**

$$R_T = f(T)$$



Switching Definitions Output Inverter

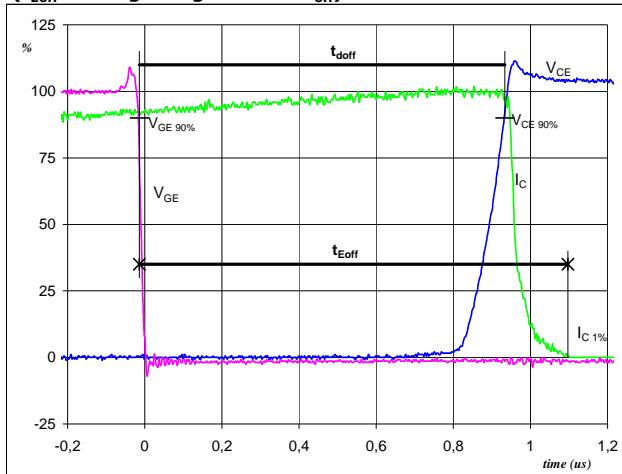
General conditions

$$T_j = 125 \text{ } ^\circ\text{C}$$

Figure 1

Output inverter IGBT

Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff}
 $(t_{Eoff} = \text{integrating time for } E_{off})$

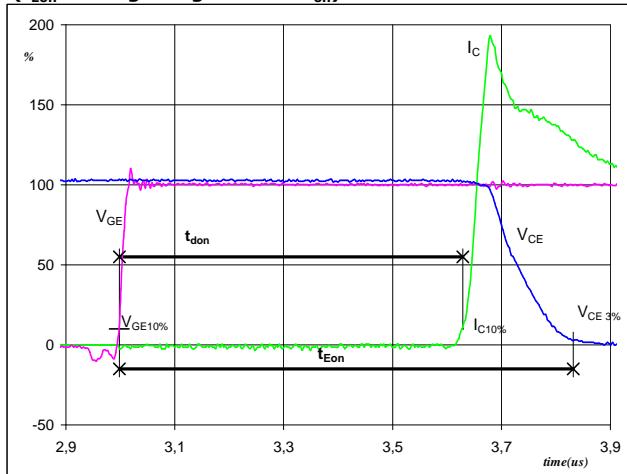


$U_{IN} (0\%) = 0 \text{ V}$
 $U_{IN} (100\%) = 5 \text{ V}$
 $V_C (100\%) = 400 \text{ V}$
 $I_C (100\%) = 6 \text{ A}$
 $t_{doff} = 0,95 \mu\text{s}$
 $t_{Eoff} = 1,11 \mu\text{s}$

Figure 2

Output inverter IGBT

Turn-on Switching Waveforms & definition of t_{don} , t_{Eon}
 $(t_{Eon} = \text{integrating time for } E_{on})$

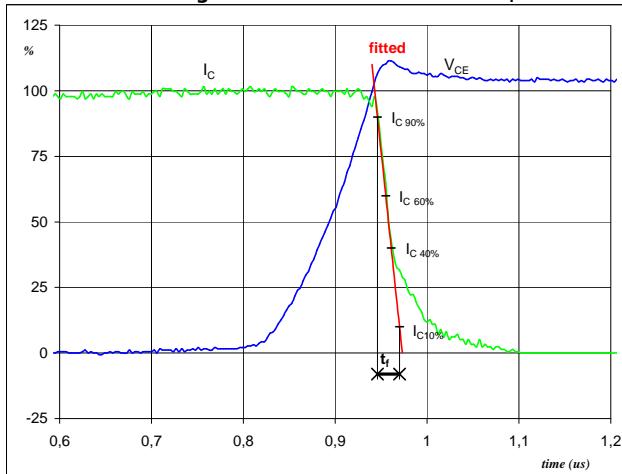


$U_{IN} (0\%) = 0 \text{ V}$
 $U_{IN} (100\%) = 5 \text{ V}$
 $V_C (100\%) = 400 \text{ V}$
 $I_C (100\%) = 6 \text{ A}$
 $t_{don} = 0,63 \mu\text{s}$
 $t_{Eon} = 0,83 \mu\text{s}$

Figure 3

Output inverter IGBT

Turn-off Switching Waveforms & definition of t_f

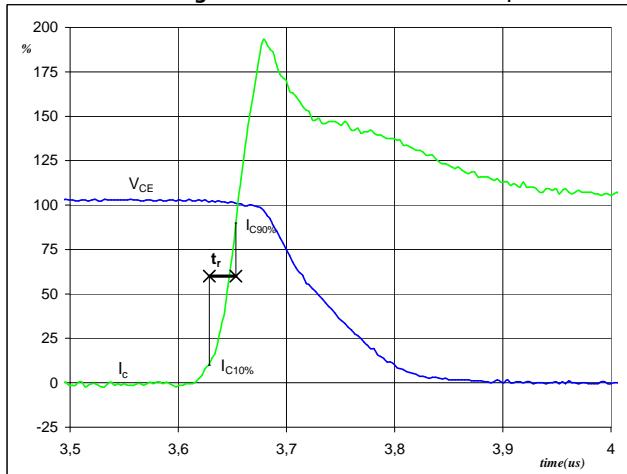


$V_C (100\%) = 400 \text{ V}$
 $I_C (100\%) = 6 \text{ A}$
 $t_f = 0,02 \mu\text{s}$

Figure 4

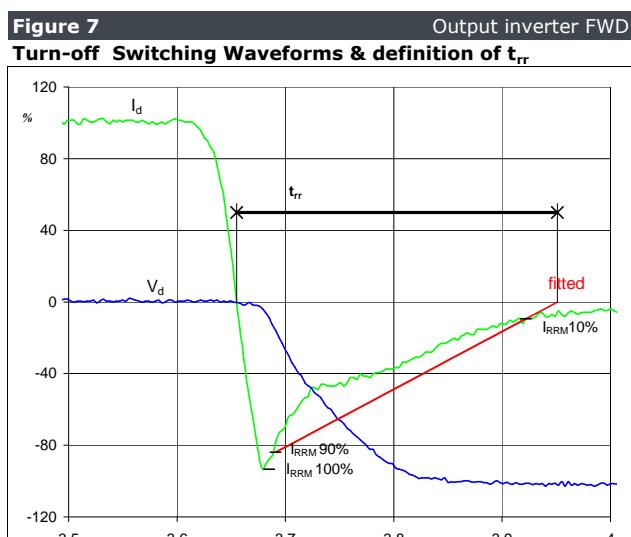
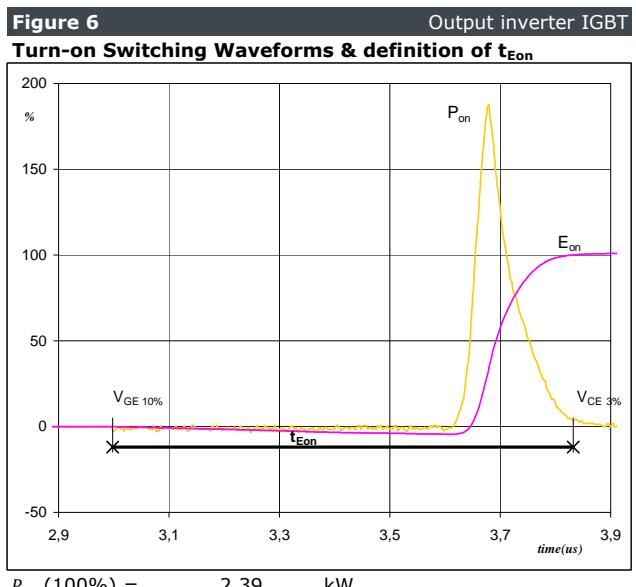
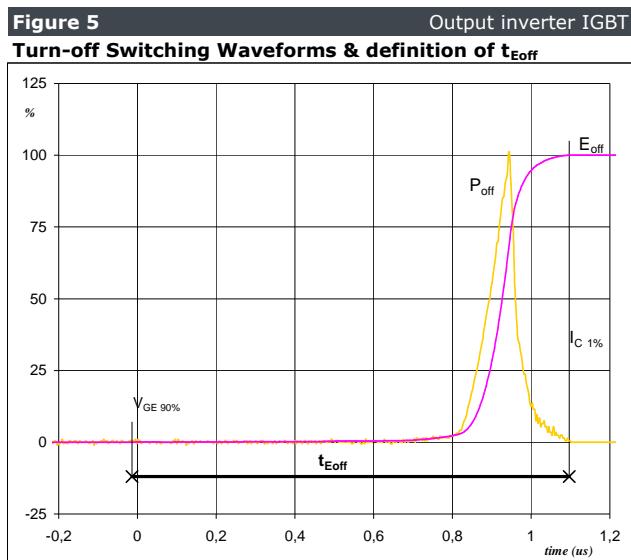
Output inverter IGBT

Turn-on Switching Waveforms & definition of t_r



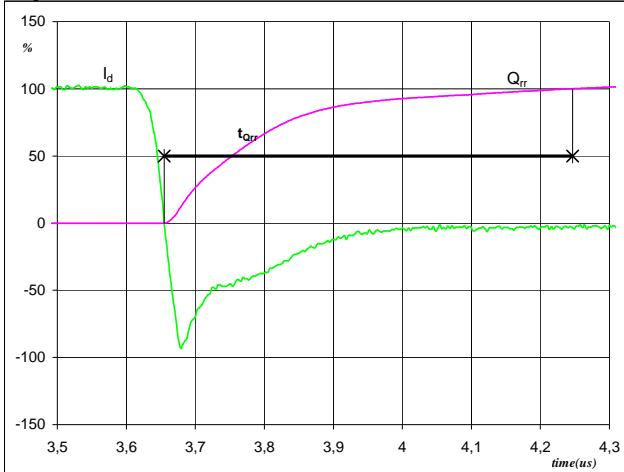
$V_C (100\%) = 400 \text{ V}$
 $I_C (100\%) = 6 \text{ A}$
 $t_r = 0,03 \mu\text{s}$

Switching Definitions Output Inverter



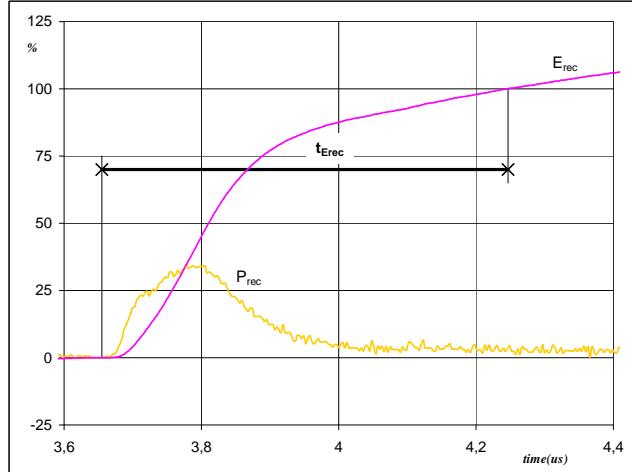
Switching Definitions Output Inverter

Figure 8 Output inverter FWD
Turn-on Switching Waveforms & definition of $t_{Q_{rr}}$
 $(t_{Q_{rr}} = \text{integrating time for } Q_{rr})$



I_d (100%) = 6 A
 Q_{rr} (100%) = 0,67 μC
 $t_{Q_{rr}} = 0,59 \mu\text{s}$

Figure 9 Output inverter FWD
Turn-on Switching Waveforms & definition of $t_{E_{rec}}$
 $(t_{E_{rec}} = \text{integrating time for } E_{rec})$

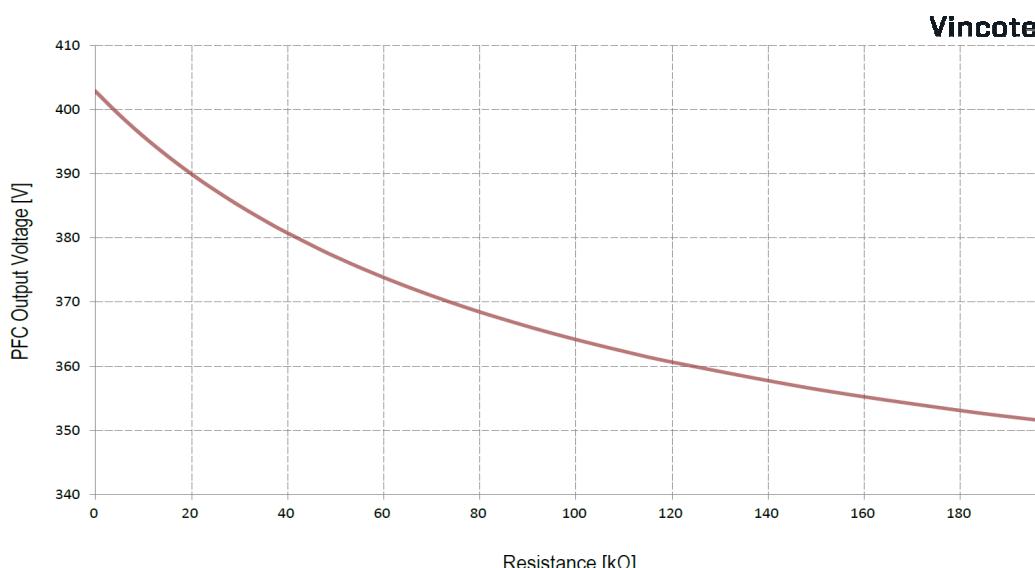
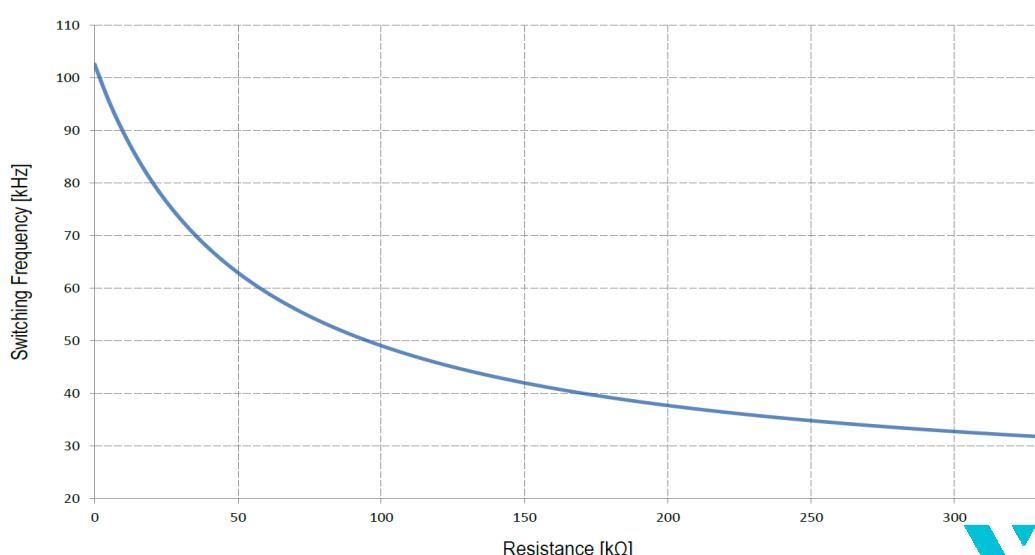


P_{rec} (100%) = 2,39 kW
 E_{rec} (100%) = 0,16 mJ
 $t_{E_{rec}} = 0,59 \mu\text{s}$

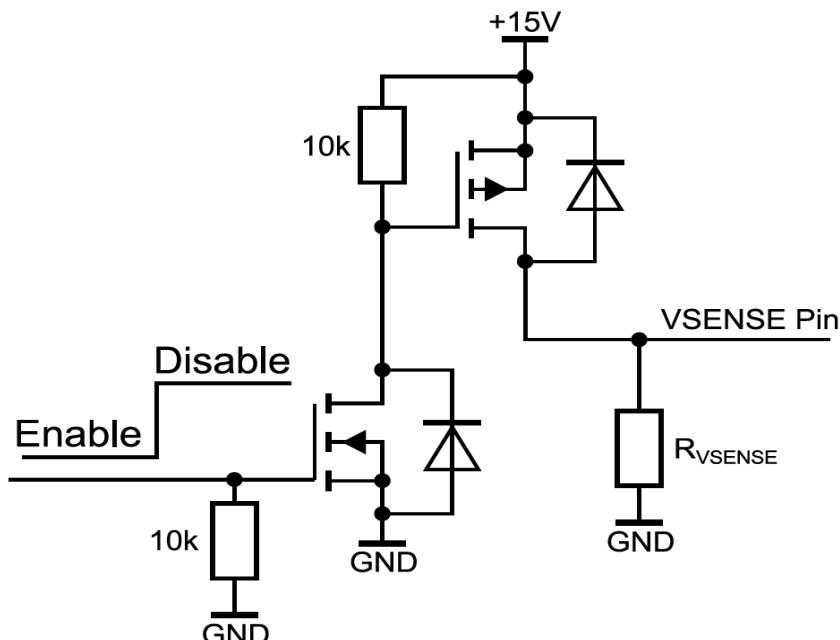
Application data

Static logic function table

V_{CC}	V_{BS}	RCIN	ITRIP	ENABLE	FAULT	LO1,2,3	HO1,2,3
$< V_{CCUV-}$	X	X	X	X	0	0	0
15V	$< V_{BSUV-}$	X	0	3.3V	High imp	/LIN1,2,3	0
15V	15V	$< 3.2V \downarrow$	0	3.3V	0	0	0
15V	15V	X	$> V_{IT,TH+}$	3.3V	0	0	0
15V	15V	$> V_{RCIN,TH}$	0	3.3V	High imp	/LIN1,2,3	/HIN1,2,3
15V	15V	$> V_{RCIN,TH}$	0	0	High imp	0	0



PFC enable circuit

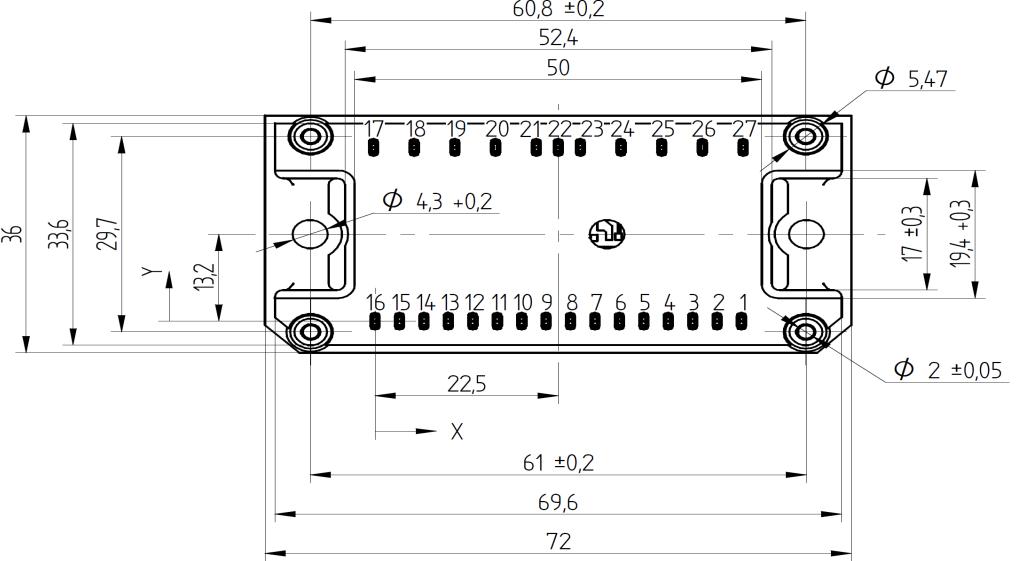


Pin Descriptions

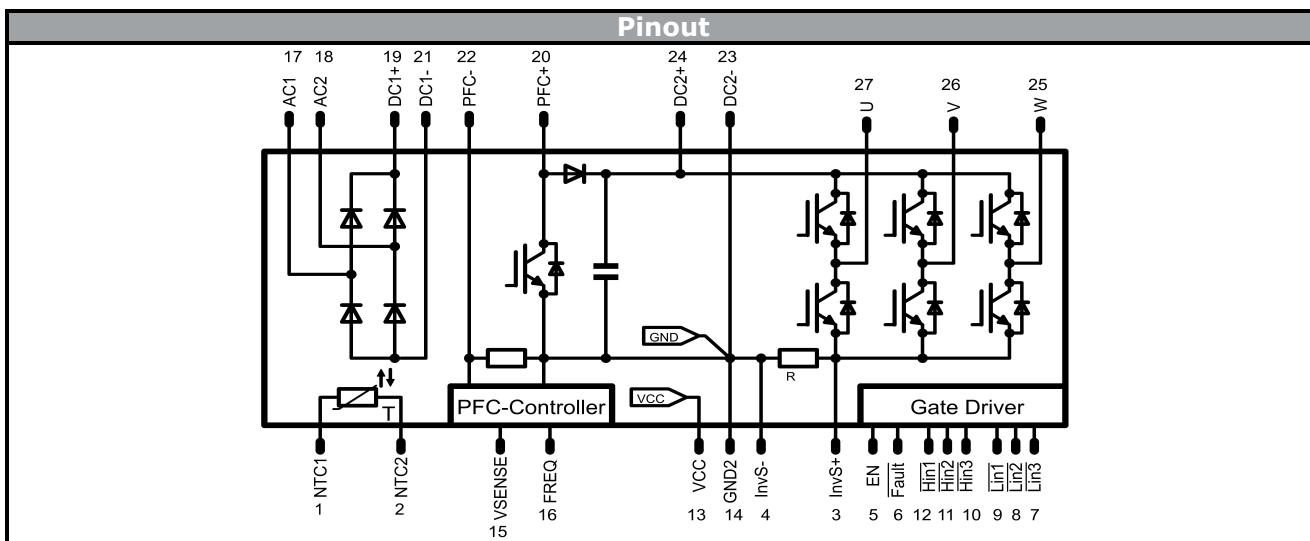
Pin #	Pin Name	Pin Description
1	NTC2	Temperature sensor connector 1
2	NTC1	Temperature sensor connector 2
3	InVS +	Inverter sense resistor high-side
4	InVS -	Inverter sense resistor low-side
5	EN	Enable I/O functionality
6	¬Fault	Fault output, indicates over current or under voltage (negative logic, open-drain output)
7	¬LIN3	Signal input for low-side W phase
8	¬LIN2	Signal input for low-side V phase
9	¬LIN1	Signal input for low-side U phase
10	¬HIN3	Signal input for high-side W phase
11	¬HIN2	Signal input for high-side V phase
12	¬HIN1	Signal input for high-side U phase
13	V _{CC}	Driver circuit supply voltage
14	GND2	Inverter ground
15	VSENSE	PFC Bulk voltage sense
16	FREQ	PFC Switching frequency adjust
17	AC1	Rectifier input
18	AC2	Rectifier input
19	DC1 + (coil)	Rectifier output DC +
20	PFC + (coil)	PFC coil connector
21	DC1 -	Rectifier output DC -
22	PFC -	PFC return
23	DC2 -	Inverter input DC -
24	DC2 +	Inverter input DC +
25	W	Output for W phase
26	V	Output for V phase
27	U	Output for U phase

Ordering Code and Marking - Outline - Pinout

Ordering Code & Marking					
Version		Ordering Code			
without thermal paste, solder pins		20-1B06IPB010RC-P955A40			
with thermal paste, solder pins		20-1B06IPB010RC-P955A40-/3/			
without thermal paste, press fit pins		20-PB06IPB010RC-P955A40Y			
with thermal paste, press fit solder pins		20-PB06IPB010RC-P955A40Y-/3/			
		Text	Name	Type&Ver	Date code
			NN-NNNNNNNNNNNNN	TTTTTTVV	WWYY
		Datamatrix	Type&Ver	Lot number	Serial
			TTTTTTVV	LLLL	SSSS
					WWYY

Outline																																																																																									
Pin table		Outline Drawing																																																																																							
<table border="1"> <thead> <tr> <th>Pin</th><th>X</th><th>Y</th></tr> </thead> <tbody> <tr><td>1</td><td>45</td><td>0</td></tr> <tr><td>2</td><td>42</td><td>0</td></tr> <tr><td>3</td><td>39</td><td>0</td></tr> <tr><td>4</td><td>36</td><td>0</td></tr> <tr><td>5</td><td>33</td><td>0</td></tr> <tr><td>6</td><td>30</td><td>0</td></tr> <tr><td>7</td><td>27</td><td>0</td></tr> <tr><td>8</td><td>24</td><td>0</td></tr> <tr><td>9</td><td>21</td><td>0</td></tr> <tr><td>10</td><td>18</td><td>0</td></tr> <tr><td>11</td><td>15</td><td>0</td></tr> <tr><td>12</td><td>12</td><td>0</td></tr> <tr><td>13</td><td>9</td><td>0</td></tr> <tr><td>14</td><td>6</td><td>0</td></tr> <tr><td>15</td><td>3</td><td>0</td></tr> <tr><td>16</td><td>0</td><td>0</td></tr> <tr><td>17</td><td>-0,2</td><td>26,4</td></tr> <tr><td>18</td><td>4,8</td><td>26,4</td></tr> <tr><td>19</td><td>9,8</td><td>26,4</td></tr> <tr><td>20</td><td>14,8</td><td>26,4</td></tr> <tr><td>21</td><td>19,8</td><td>26,4</td></tr> <tr><td>22</td><td>22,5</td><td>26,4</td></tr> <tr><td>23</td><td>25,2</td><td>26,4</td></tr> <tr><td>24</td><td>30,2</td><td>26,4</td></tr> <tr><td>25</td><td>35,2</td><td>26,4</td></tr> <tr><td>26</td><td>40,2</td><td>26,4</td></tr> <tr><td>27</td><td>45,2</td><td>26,4</td></tr> </tbody> </table>		Pin	X	Y	1	45	0	2	42	0	3	39	0	4	36	0	5	33	0	6	30	0	7	27	0	8	24	0	9	21	0	10	18	0	11	15	0	12	12	0	13	9	0	14	6	0	15	3	0	16	0	0	17	-0,2	26,4	18	4,8	26,4	19	9,8	26,4	20	14,8	26,4	21	19,8	26,4	22	22,5	26,4	23	25,2	26,4	24	30,2	26,4	25	35,2	26,4	26	40,2	26,4	27	45,2	26,4				
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Ordering Code and Marking - Outline - Pinout



Identification

ID	Component	Voltage	Current	Function	Comment
T1,T2,T3,T4,T5,T6	IGBT	600 V	10 A	Inverter Transistor	
T7	IGBT	650 V	30 A	PFC IGBT	
D12	FWD	650 V	30 A	PFC Diode	
D11	FWD	650 V	6 A	PFC Inverse Diode	
R3	Resistor			PFC Shunt	
D7,D8,D9,D10	Rectifier	1600 V	12 A	Input Rectifier Diode	
R2	Resistor			DC Shunt	
C1	Capacitor	500 V		DC Link Capacitor	
T	Thermistor			Thermistor	

Packaging instruction					
Standard packaging quantity (SPQ)	100	>SPQ	Standard	<SPQ	Sample
Handling instruction					
Handling instructions for <i>flow</i> 1B packages see vincotech.com website.					
Package data					
Package data for <i>flow</i> 1B packages see vincotech.com website.					
UL recognition and file number					
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.					
					

Document No.:	Date:	Modification:	Pages
20-xB06IPB010RC-P955A40x-D8-14	08 Apr. 2017	Page number correction	6

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